

## N-Channel 30-V(D-S) MOSFET

| V(BR)DSS | RDS(on)MAX            | ID   |
|----------|-----------------------|------|
| 30 V     | 32mΩ@10V<br>35mΩ@4.5V | 5.8A |

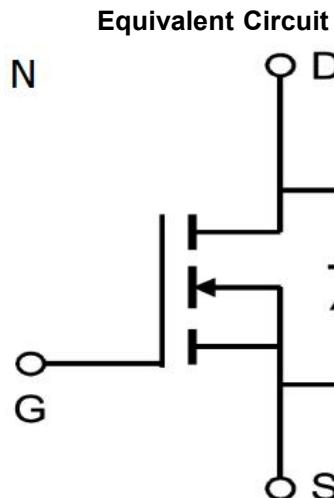
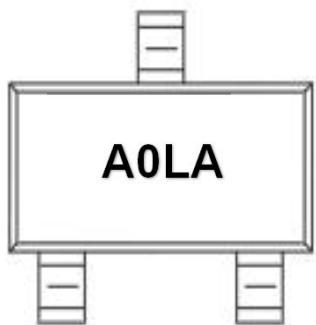
### FEATURE

- ※ TrenchFET Power MOSFET

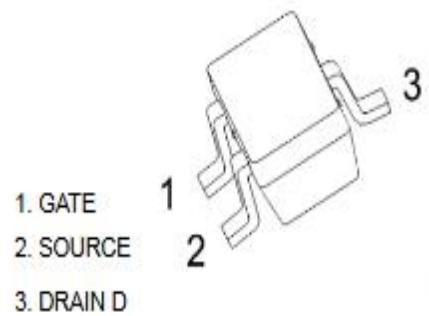
### APPLICATION

- ※ Load Switch for Portable Devices
- ※ DC/DC Converter

### MARKING



**SOT-23-3L**



### Maximum ratings ( Ta=25°C unless otherwise noted)

| Parameter  | Symbol           | Value    | Unit |
|--|------------------|----------|------|
| Drain-Source Voltage                               | VDS              | 30       | V    |
| Gate-Source Voltage                                | VGS              | ±12      |      |
| Continuous Drain Current                           | ID               | 5.8      | A    |
| Pulsed Diode Current                               | IDM              | 30       |      |
| Continuous Source-Drain Current(Diode Conduction)  | IS               | 0.8      |      |
| Power Dissipation                                  | PD               | 1.4      | W    |
| Thermal Resistance from Junction to Ambient (t≤5s) | R <sub>θJA</sub> | 125      | °C/W |
| Operating Junction                                 | T <sub>J</sub>   | 150      | °C   |
| Storage Temperature                                | T <sub>STG</sub> | -55~+150 | °C   |

## MOSFET ELECTRICAL CHARACTERISTICS

**Static Electrical Characteristics (Ta = 25 °C Unless Otherwise Noted)**

| Parameter                                      | Symbol   | Test Condition                                    | Min | Typ | Max  | Unit |
|--|----------|---|-----|-----|------|------|
| <b>Static</b>                                  |          |   |     |     |      |      |
| Drain-source breakdown voltage                 | V(BR)DSS | VGS = 0V, ID = 250µA                              | 30  |     |      | V    |
| Gate-source threshold voltage                  | VGS(th)  | VDS = VGS, ID = 250µA                             | 0.6 |     | 1.2  | V    |
| Gate-source leakage                            | IGSS     | VDS = 0V, VGS = ±12V                              |     |     | ±100 | nA   |
| Zero gate voltage drain current                | IDSS     | VDS = 24V, VGS = 0V                               |     |     | 1    | µA   |
| Drain-source on-state resistancea              | RDS(on)  | VGS = 10V, ID = 2.8A                              |     | 22  | 32   | mΩ   |
|  |          | VGS = 4.5V, ID = 2.0A                             |     | 25  | 35   | mΩ   |
| Forward transconductancea                      | gfs      | VDS = 4.5V, ID = 5A                               |     | 15  |      | S    |
| Diode forward voltage                          | VSD      | IS=1A, VGS=0V                                     |     | 0.7 | 1.3  | V    |
| <b>Dynamic</b>                                 |          |   |     |     |      |      |
| Input capacitance                              | Ciss     | VDS = 15V, VGS = 0V,<br>f=1MHz                    |     | 823 | 1050 | pF   |
| Output capacitance                             | Coss     |   |     | 99  |      | pF   |
| Reverse transfer capacitanceb                  | Crss     |   |     | 77  |      | pF   |
| Total gate charge                              | Qg       | VDS = 10V, VGS = 4.5V,<br>ID = -4.5A              |     | 11  | 14   | nC   |
| Gate-source charge                             | Qgs      |   |     | 1.3 |      | nC   |
| Gate-drain charge                              | Qgd      |   |     | 2.8 |      | nC   |
| Gate resistance                                | Rg       | f=1MHz  |     |     | 3.6  | Ω    |
| <b>Switchingb</b>                              |          |   |     |     |      |      |
| Turn-on delay time                             | td(on)   | VDD= 10V<br>RL=10Ω, ID ≈ 1A,<br>VGEN= 4.5V, Rg=6Ω |     | 7   | 15   | ns   |
| Rise time                                      | tr       |   |     | 15  | 20   | ns   |
| Turn-off delay time                            | td(off)  |   |     | 38  | 50   | ns   |
| Fall time                                      | tf       |   |     | 3   | 10   | ns   |
| <b>Drain-source body diode characteristics</b> |          |   |     |     |      |      |
| Continuous Source-Drain Diode Current          | IS       | Tc=25°C   |     |     | 1.2  | A    |
| Pulsed Diode forward Current                   | ISM      |   |     |     | 20   | A    |

### Note :

1. Repetitive Rating : Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t < 5 sec.
3. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤ 2%.
4. Guaranteed by design not subject to production testing

## Typical Characteristics :

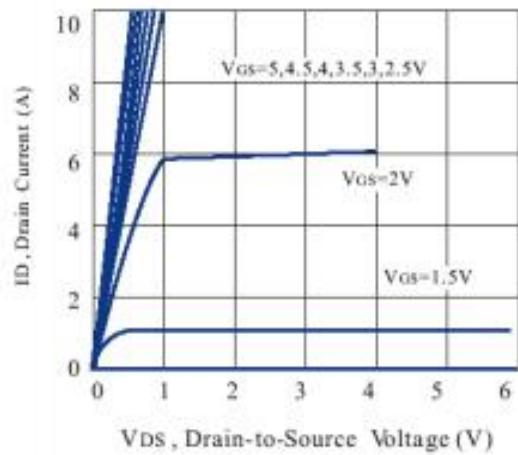


Figure 1. Output Characteristics

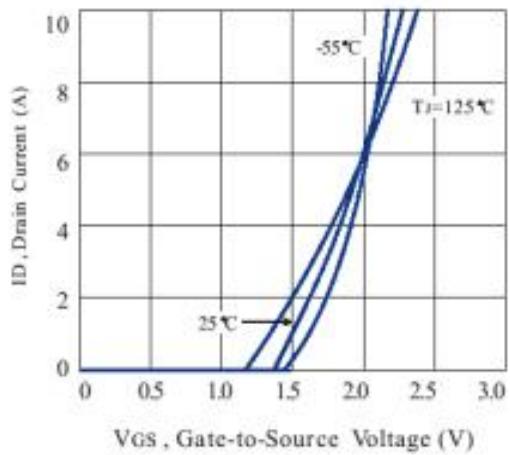


Figure 2. Transfer Characteristics

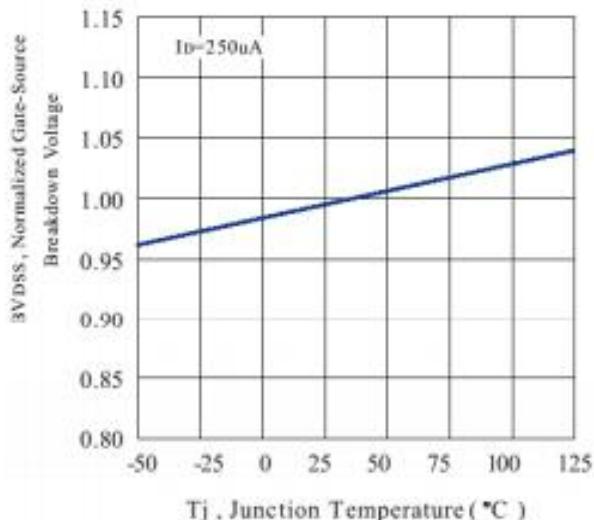


Figure 3. Breakdown Voltage Variation with Temperature

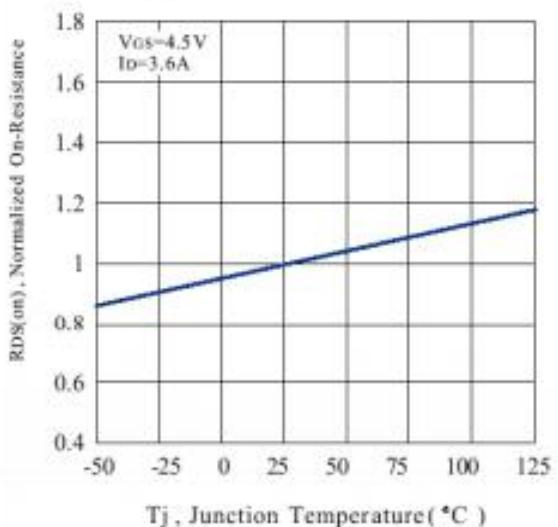


Figure 4. On-Resistance Variation with Temperature

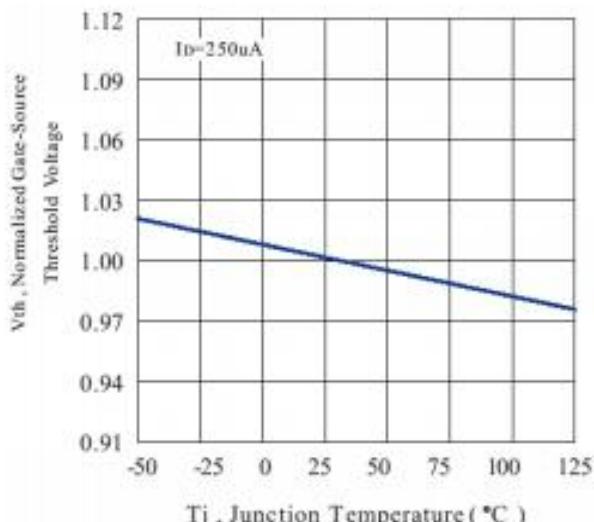


Figure 5. Gate Threshold Variation with Temperature

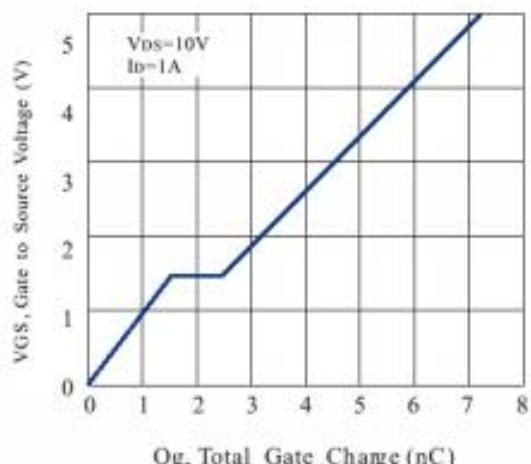
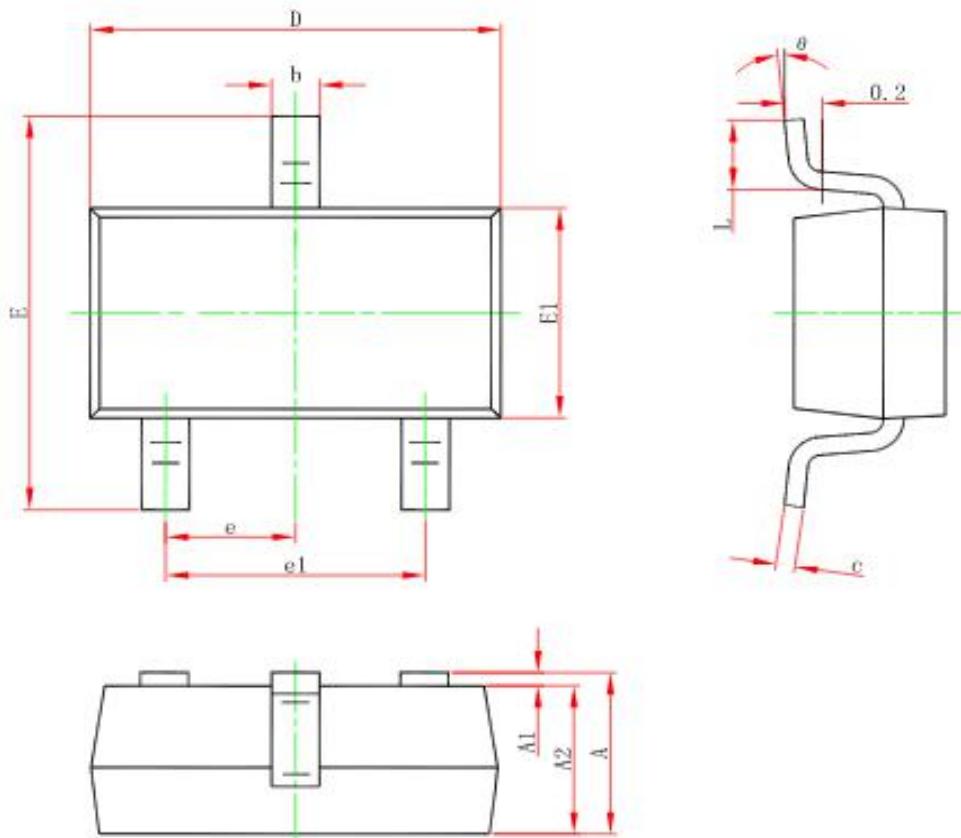


Figure 6. Gate Charge

## SOT-23-3L PACKAGE OUTLINE DIMENSIONS



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 1.050                     | 1.250 | 0.041                | 0.049 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 1.050                     | 1.150 | 0.041                | 0.045 |
| b      | 0.300                     | 0.500 | 0.012                | 0.020 |
| c      | 0.100                     | 0.200 | 0.004                | 0.008 |
| D      | 2.820                     | 3.020 | 0.111                | 0.119 |
| E1     | 1.500                     | 1.700 | 0.059                | 0.067 |
| E      | 2.650                     | 2.950 | 0.104                | 0.116 |
| e      | 0.950(BSC)                |       | 0.037(BSC)           |       |
| e1     | 1.800                     | 2.000 | 0.071                | 0.079 |
| L      | 0.300                     | 0.600 | 0.012                | 0.024 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |